

To our customers,

Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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MOS FIELD EFFECT TRANSISTOR μ PA2719AGR

SWITCHING P-CHANNEL POWER MOS FET

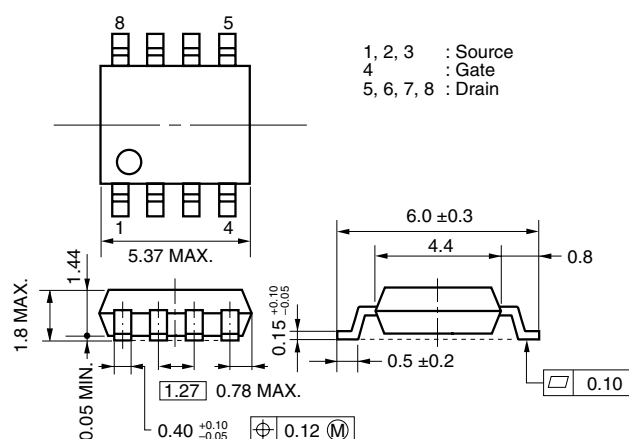
DESCRIPTION

The μ PA2719AGR is P-Channel MOS Field Effect Transistor designed for power management applications of notebook computers and Lithium-Ion battery protection circuit.

FEATURES

- Low on-state resistance
 $R_{DS(on)1} = 13 \text{ m}\Omega \text{ MAX. (} V_{GS} = -10 \text{ V, } I_D = -5.0 \text{ A)}$
 $R_{DS(on)2} = 20.9 \text{ m}\Omega \text{ MAX. (} V_{GS} = -4.5 \text{ V, } I_D = -5.0 \text{ A)}$
- Low input capacitance
 $C_{iss} = 2010 \text{ pF TYP.}$
- Built-in gate protection diode
- Small and surface mount package (Power SOP8)

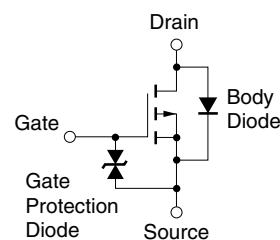
PACKAGE DRAWING (Unit: mm)



ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, All terminals are connected.)

Drain to Source Voltage (V _{GS} = 0 V)	V _{DSS}	-30	V
Gate to Source Voltage (V _{DS} = 0 V)	V _{GSS}	±20	V
Drain Current (DC)	I _{D(DC)}	±10	A
Drain Current (pulse) ^{Note1}	I _{D(pulse)}	±100	A
Total Power Dissipation ^{Note2}	P _{T1}	2	W
Total Power Dissipation ^{Note3}	P _{T2}	2	W
Channel Temperature	T _{ch}	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C
Single Avalanche Current ^{Note4}	I _{AS}	-10	A
Single Avalanche Energy ^{Note4}	E _{AS}	10	mJ

EQUIVALENT CIRCUIT



Notes 1. PW ≤ 10 μs, Duty Cycle ≤ 1%

2. Mounted on ceramic substrate of 1200 mm² x 2.2 mm
3. Mounted on glass epoxy board of 25.4 mm x 25.4 mm x 0.8 mm, PW = 10 sec
4. Starting T_{ch} = 25°C, V_{DD} = -15 V, R_G = 25 Ω, L = 100 μH, V_{GS} = -20 → 0 V

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

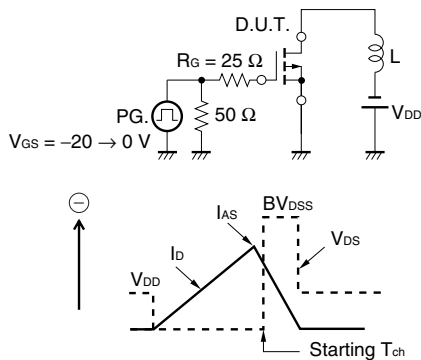
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ELECTRICAL CHARACTERISTICS (T_A = 25°C, All terminals are connected.)

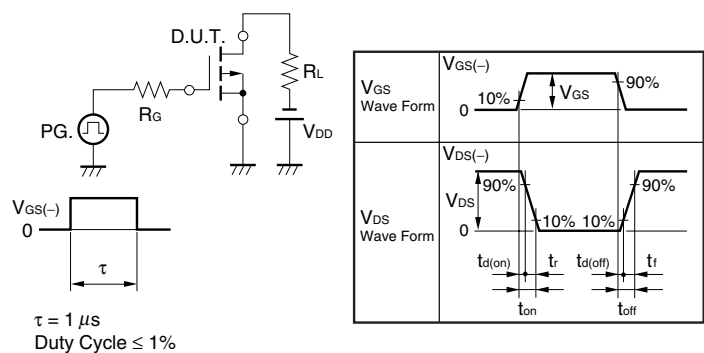
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = -30 V, V _{GS} = 0 V			-1	μA
Gate Leakage Current	I _{GSS}	V _{GS} = ±20 V, V _{DS} = 0 V			±10	μA
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = -10 V, I _D = -1 mA	-1.0		-2.5	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = -10 V, I _D = -5.0 A	8			S
Drain to Source On-state Resistance Note	R _{DS(on)1}	V _{GS} = -10 V, I _D = -5.0 A		10.6	13	mΩ
	R _{DS(on)2}	V _{GS} = -4.5 V, I _D = -5.0 A		14.2	20.9	mΩ
	R _{DS(on)3}	V _{GS} = -4.0 V, I _D = -5.0 A		16.6	25.5	mΩ
Input Capacitance	C _{iss}	V _{DS} = -10 V		2010		pF
Output Capacitance	C _{oss}	V _{GS} = 0 V		460		pF
Reverse Transfer Capacitance	C _{rss}	f = 1 MHz		350		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = -15 V, I _D = -5.0 A		12		ns
Rise Time	t _r	V _{GS} = -10 V		15		ns
Turn-off Delay Time	t _{d(off)}	R _G = 10 Ω		290		ns
Fall Time	t _f			180		ns
Total Gate Charge	Q _G	V _{DD} = -24 V		43		nC
Gate to Source Charge	Q _{GS}	V _{GS} = -10 V		5.5		nC
Gate to Drain Charge	Q _{GD}	I _D = -10 A		12		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	I _F = 10 A, V _{GS} = 0 V		0.84		V
Reverse Recovery Time	t _{rr}	I _F = 10 A, V _{GS} = 0 V		105		ns
Reverse Recovery Charge	Q _{rr}	di/dt = 50 A/μs		6.7		nC

Note Pulsed

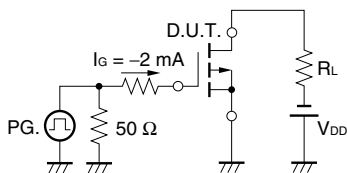
TEST CIRCUIT 1 AVALANCHE CAPABILITY



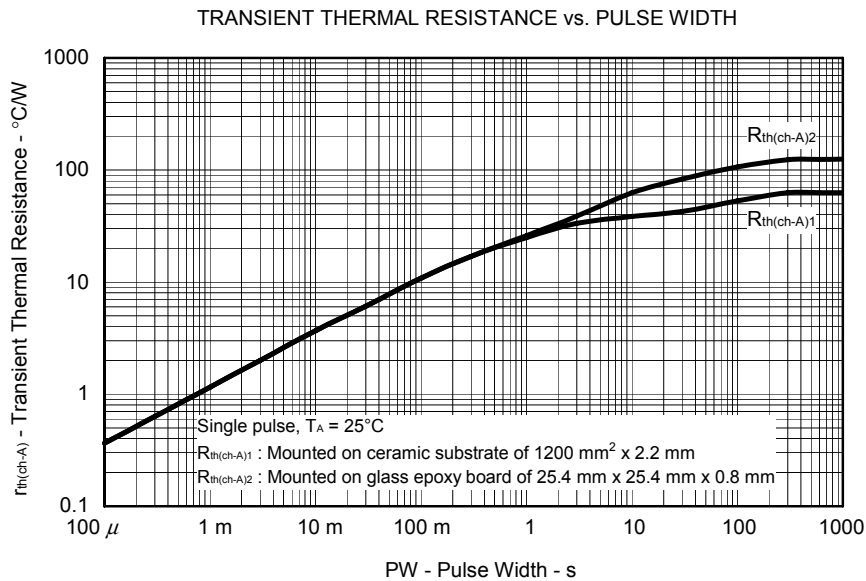
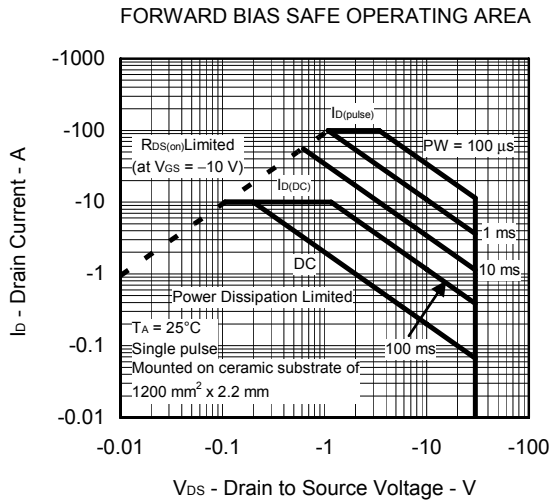
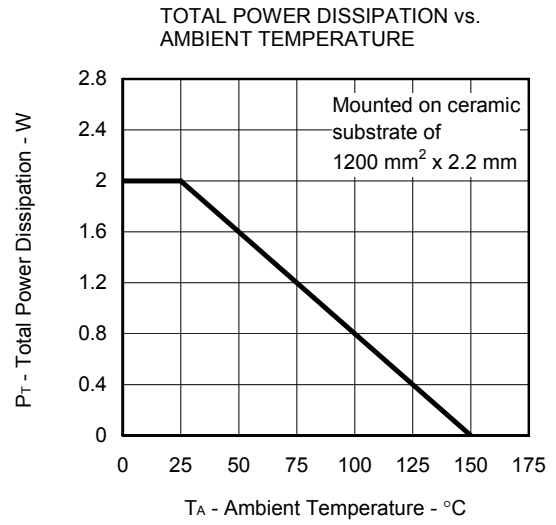
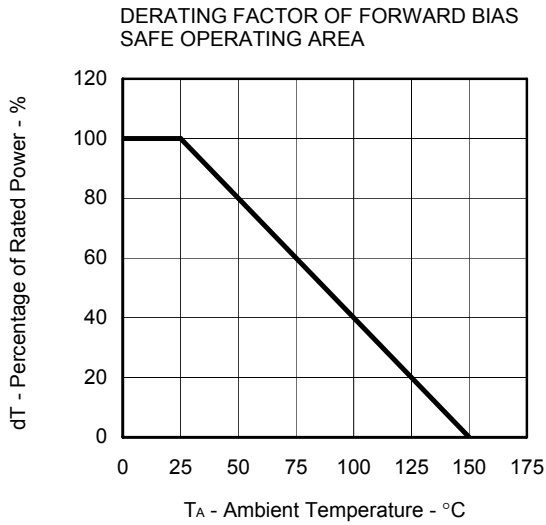
TEST CIRCUIT 2 SWITCHING TIME



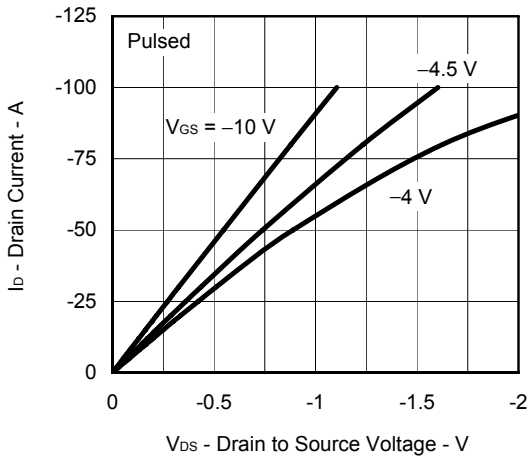
TEST CIRCUIT 3 GATE CHARGE



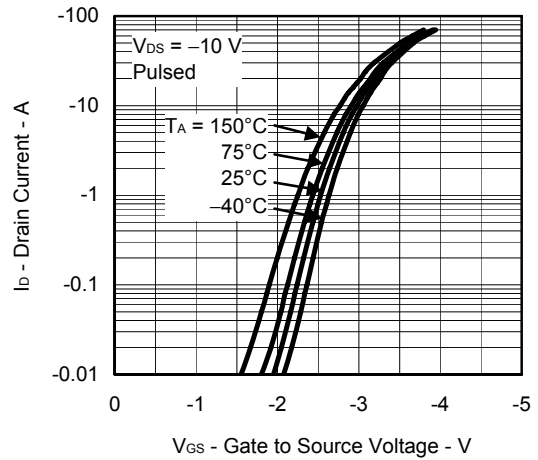
ELECTRICAL CHARACTERISTICS (T_A = 25°C)



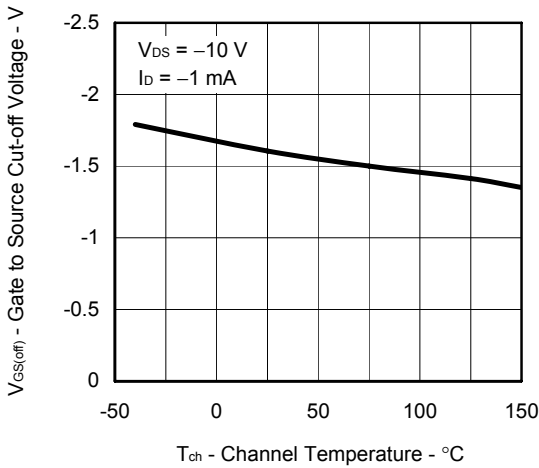
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



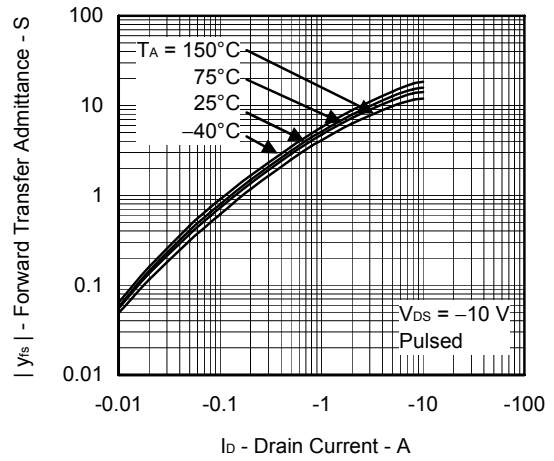
FORWARD TRANSFER CHARACTERISTICS



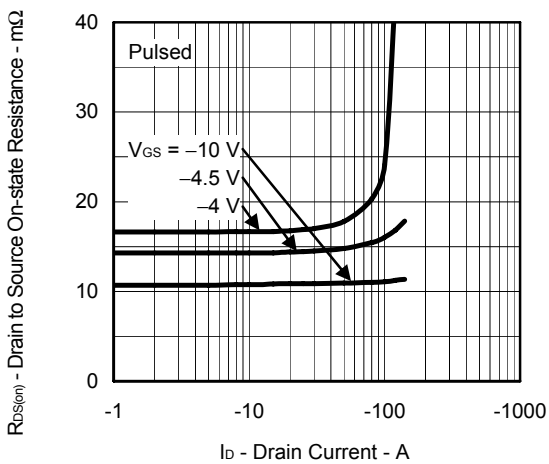
GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



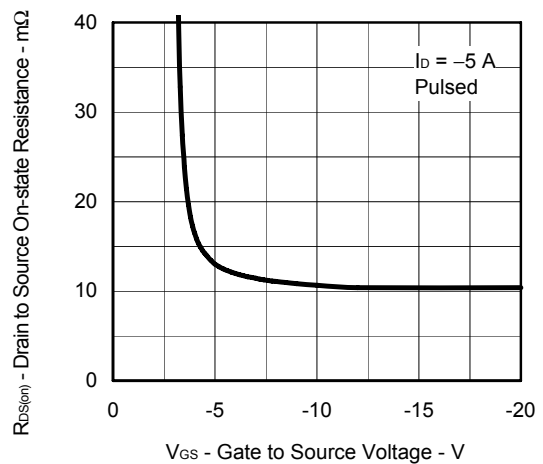
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



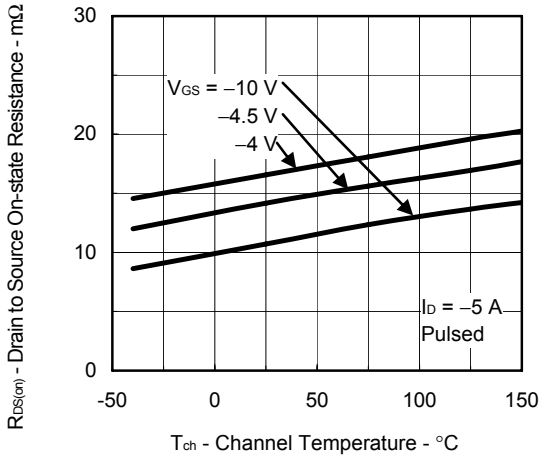
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



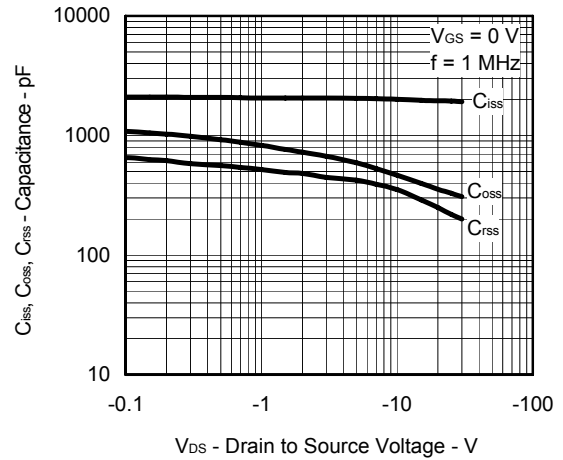
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



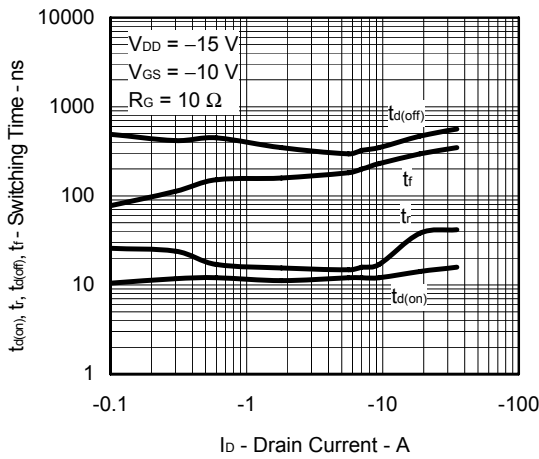
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



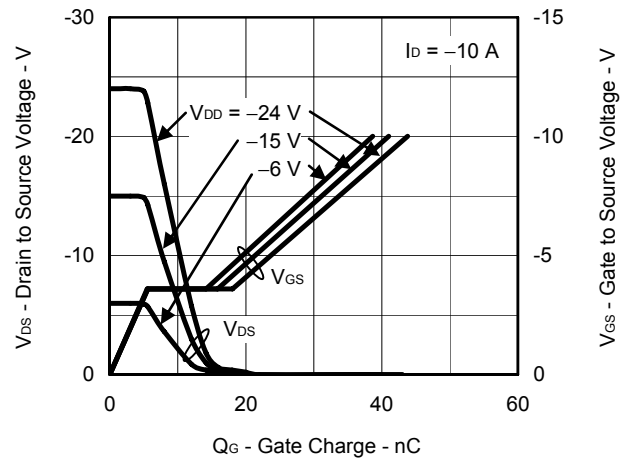
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



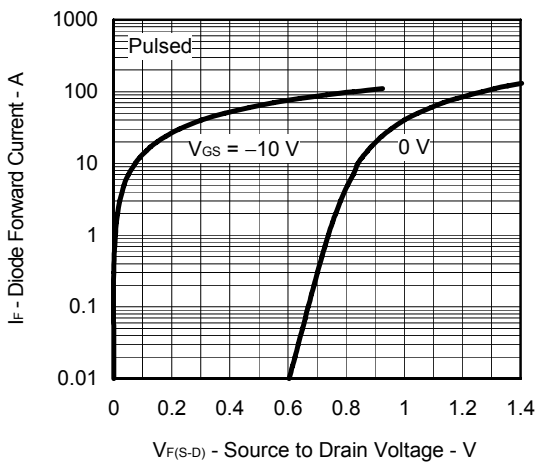
SWITCHING CHARACTERISTICS



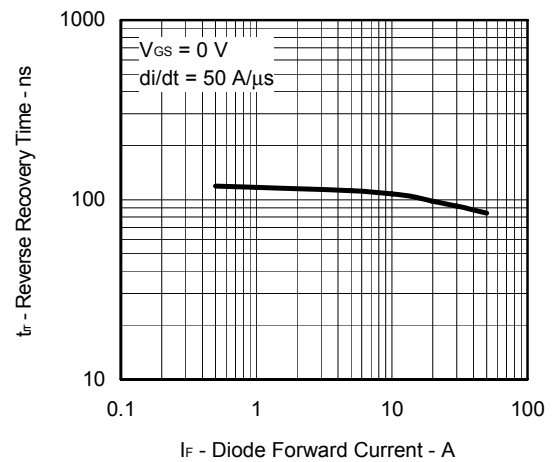
DYNAMIC INPUT/OUTPUT CHARACTERISTICS

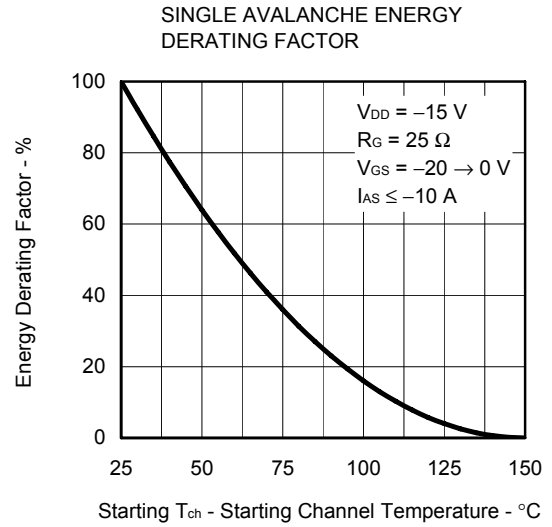
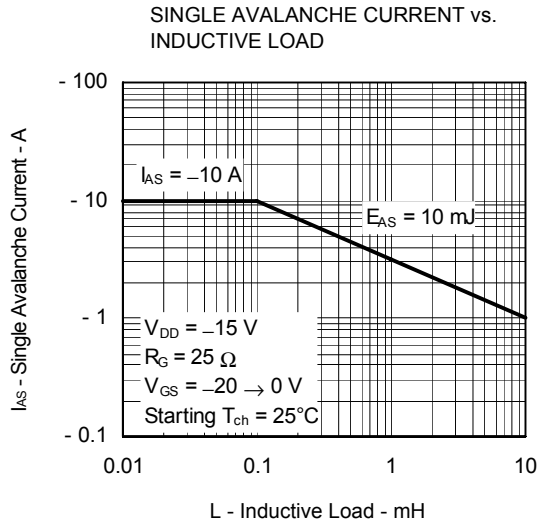


SOURCE TO DRAIN DIODE FORWARD VOLTAGE



REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT





ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE
μ PA2719AGR-E1-AT ^{Note}	Pure Sn (Tin)	Tape 2500 p/reel	Power SOP8
μ PA2719AGR-E2-AT ^{Note}			0.08 g TYP.

Note Pb-free (This product does not contain Pb in external electrode and other parts.)

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